

1200V, 40A, Trench FS II Fast IGBT

General Description

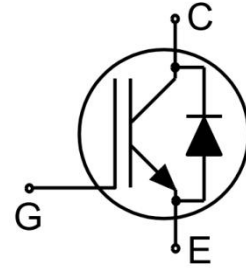
Using NCE's proprietary trench design and advanced FS (Field Stop) second generation technology, the 1200V Trench FSII IGBT offers superior conduction and switching performances, and easy parallel operation;

Features

- Trench FSII Technology Offering
- Very low $V_{CE(sat)}$
- High speed switching
- Positive temperature coefficient in $V_{CE(sat)}$
- Very tight parameter distribution
- High ruggedness, temperature stable behavior

Application

- Welding



Schematic diagram

Package Marking and Ordering Information

Device	Device Package	Device Marking
NCE40TD120WW	TO-264	NCE40TD120WW



TO-264

Absolute Maximum Ratings ($T_C=25^{\circ}\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Units
V_{CES}	Collector-Emitter Voltage	1200	V
V_{GES}	Gate- Emitter Voltage	± 30	V
I_C	Collector Current	80	A
	Collector Current @ $T_C = 100^{\circ}\text{C}$	40	A
I_{Cpuls}	Pulsed Collector Current, t_p limited by T_{jmax}	160	A
-	turn off safe operating area, $V_{CE}=1200\text{V}$, $T_j=175^{\circ}\text{C}$	160	A
I_F	Diode Continuous Forward Current @ $T_C = 100^{\circ}\text{C}$	40	A
I_{FM}	Diode Maximum Forward Current	160	A
P_D	Power Dissipation @ $T_C = 25^{\circ}\text{C}$	468	W
	Power Dissipation @ $T_C = 100^{\circ}\text{C}$	234	W
T_J, T_{stg}	Operating Junction and Storage Temperature Range	-55 to +175	$^{\circ}\text{C}$
T_L	Maximum Temperature for Soldering	260	$^{\circ}\text{C}$

Thermal Characteristic

Symbol	Parameter	Value	Units
$R_{\theta JC}$	Thermal Resistance, Junction to case for IGBT	0.32	$^{\circ}\text{C/W}$
$R_{\theta JC}$	Thermal Resistance, Junction to case for Diode	0.75	$^{\circ}\text{C/W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	40	$^{\circ}\text{C/W}$

Electrical Characteristics ($T_c=25^{\circ}\text{C}$ unless otherwise noted)

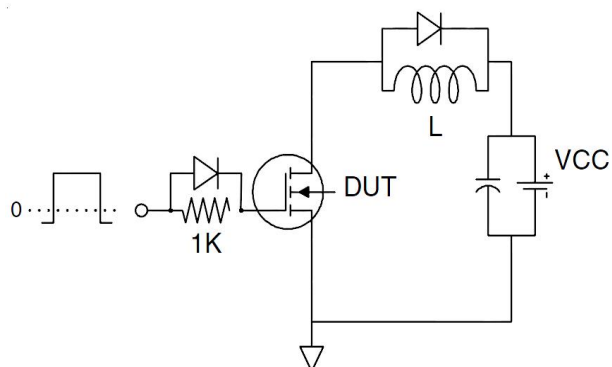
Symbol	Parameter	Conditions	Value			Units	
			Min.	Typ.	Max.		
Static Characteristics							
$V_{(BR)CES}$	Collector-Emitter Breakdown Voltage	$V_{GE}=0V, I_{CE}=1mA$	1200	--	--	V	
I_{CES}	Collector-Emitter Leakage Current	$V_{GE}=0V, V_{CE}=1200V$	--	--	200	uA	
$I_{GES(F)}$	Gate to Emitter Forward Leakage	$V_{GE}=+30V, V_{CE}=0V$	--	--	200	nA	
$I_{GES(R)}$	Gate to Emitter Reverse Leakage	$V_{GE}=-30V, V_{CE}=0V$	--	--	200	nA	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C=40A$ $V_{GE}=15V$	$T_J=25^{\circ}C$	--	1.9	2.4	V
			$T_J=175^{\circ}C$	--	2.2	--	V
$V_{GE(th)}$	Gate Threshold Voltage	$I_C=1mA, V_{CE}=V_{GE}$	4.5	--	6.5	V	
Dynamic Characteristics							
C_{ies}	Input Capacitance	$V_{CE}=30V, V_{GE}=0V,$ $f=1MHz$	--	6190	--	pF	
C_{oes}	Output Capacitance		--	185	--		
C_{res}	Reverse Transfer Capacitance		--	133	--		
Q_g	Total Gate Charge	$V_{CC}=960V, I_C=40A,$ $V_{GE}=15V$	--	242	--	nC	
Q_{ge}	Gate to Emitter Charge		--	51	--		
Q_{gc}	Gate to Collector Charge		--	115	--		
Switching Characteristics							
$t_{d(ON)}$	Turn-on Delay Time	$V_{CE}=600V, I_C=40A,$ $V_{GE}=0/15V, R_g=8\Omega$ Inductive Load	--	19	--	ns	
t_r	Rise Time		--	17	--		
$t_{d(OFF)}$	Turn-Off Delay Time		--	170	--		
t_f	Fall Time		--	18	--		
E_{on}	Turn-On Switching Loss		--	2.1	--	mJ	
E_{off}	Turn-Off Switching Loss		--	1.2	--		
E_{ts}	Total Switching Loss		--	3.3	--		

Electrical Characteristics of the Diode ($T_c=25^{\circ}\text{C}$ unless otherwise specified)

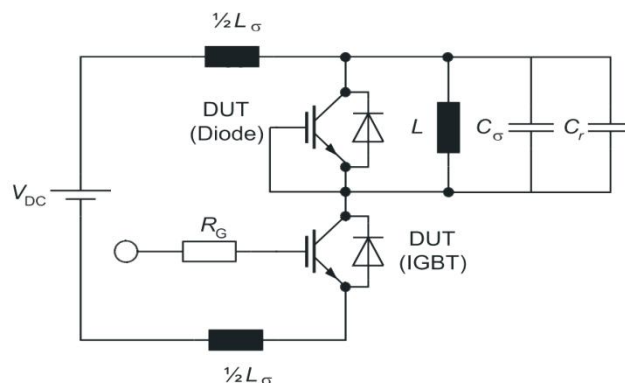
Symbol	Parameter	Conditions	Rating			Units
			Min.	Typ.	Max.	
V _{FM}	Diode Forward Voltage	I _F =20A	--	2.1	2.8	V
T _{rr}	Reverse Recovery Time	I _F =20A, di/dt=500A/us	--	203	--	ns
I _{RRM}	Diode Peak Reverse Recovery Current		--	10	--	A
Q _{rr}	Reverse Recovery Charge		--	1.1	--	uC
Pulse width t _{tp} ≤380μs,δ≤2%						

Test Circuit

1) Gate Charge Test Circuit

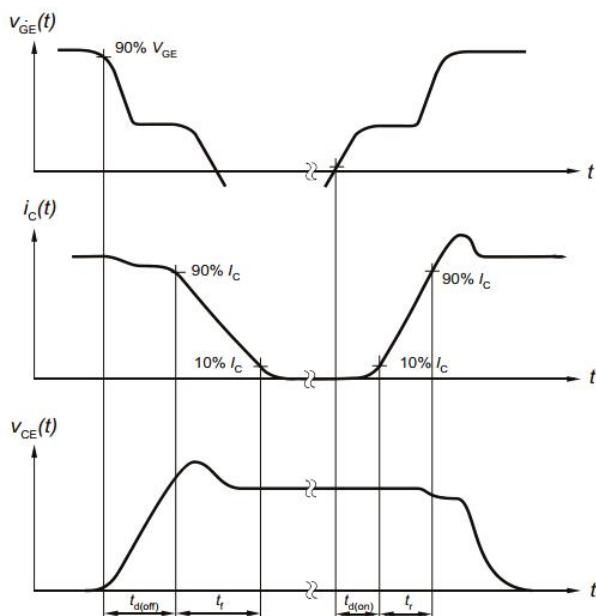


2) Switch Time Test Circuit

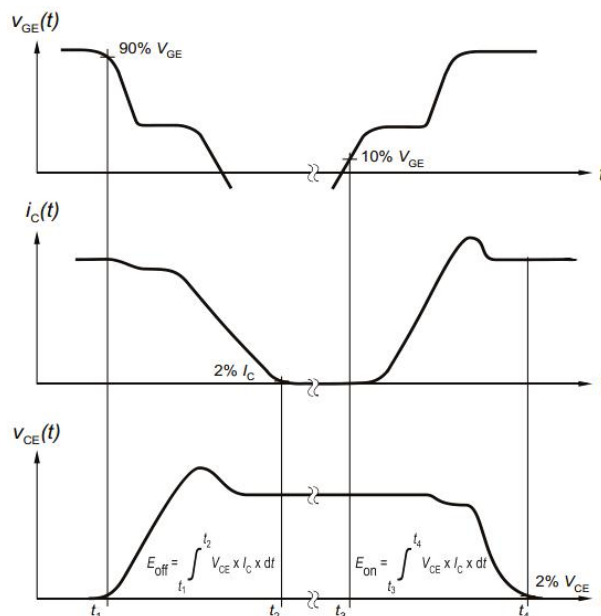


Switching characteristics

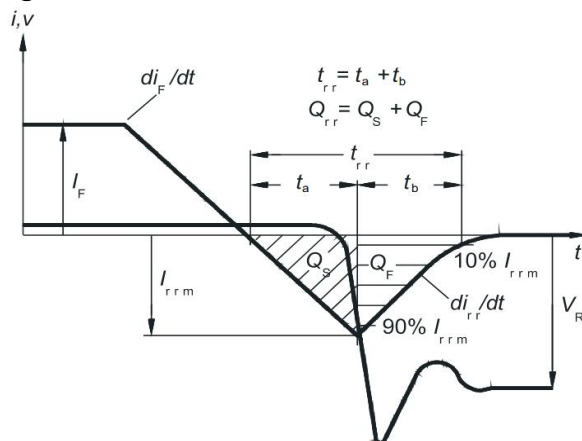
1) Definition of switching times



2) Definition of switching losses



3) Definition of diode switching characteristics



Typical Electrical and Thermal Characteristics

Figure 1 Output Characteristics

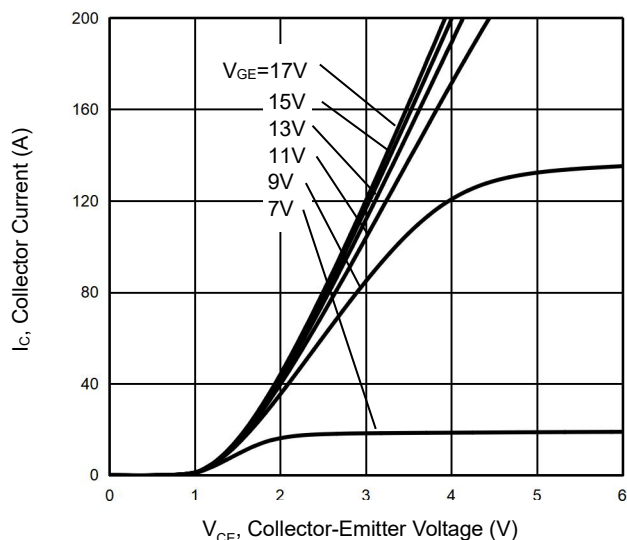


Figure 2 Transfer Characteristics

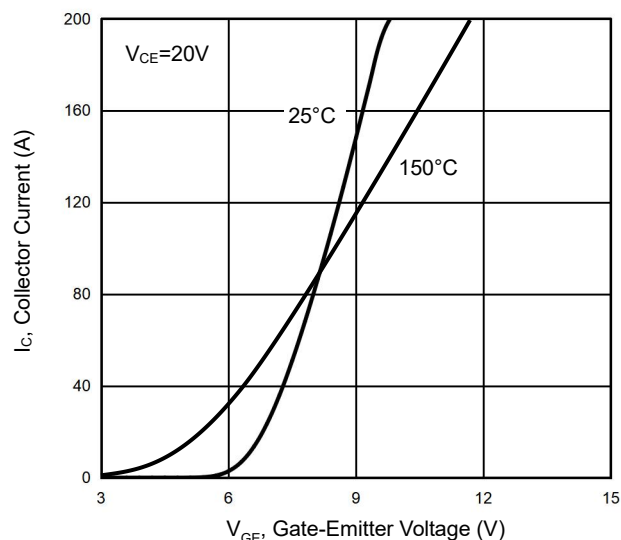


Figure 3 $V_{CE(sat)}$ vs. Case Temperature

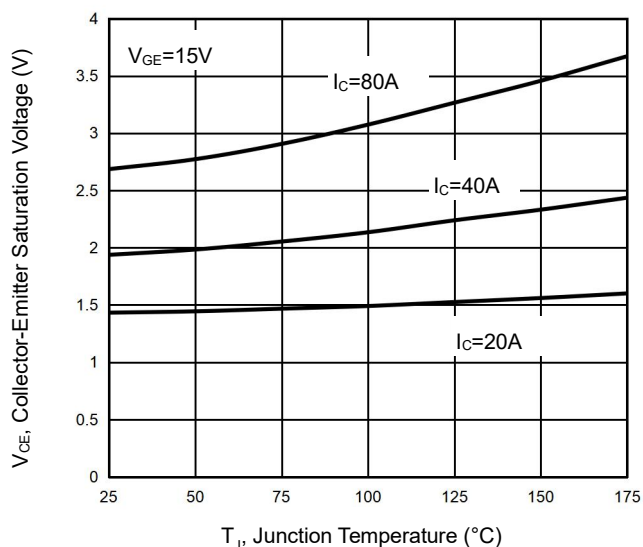


Figure 4 Saturation Voltage vs. V_{GE}

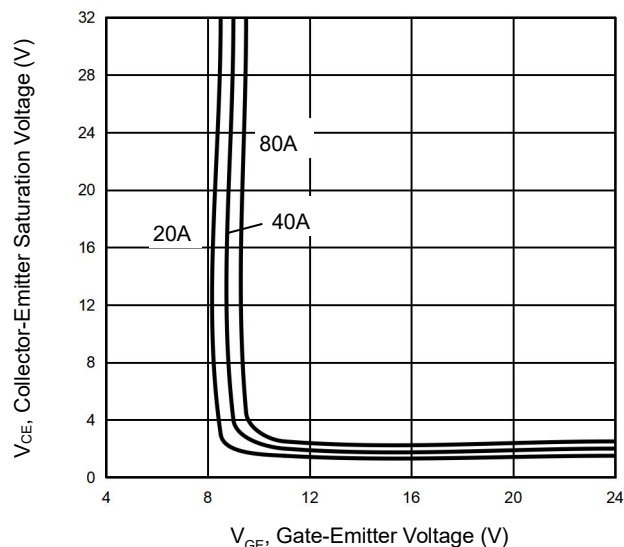


Figure 5 Capacitance Characteristics

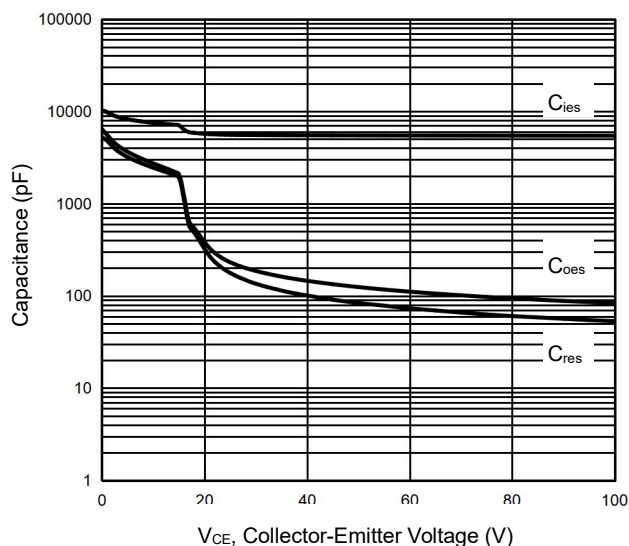
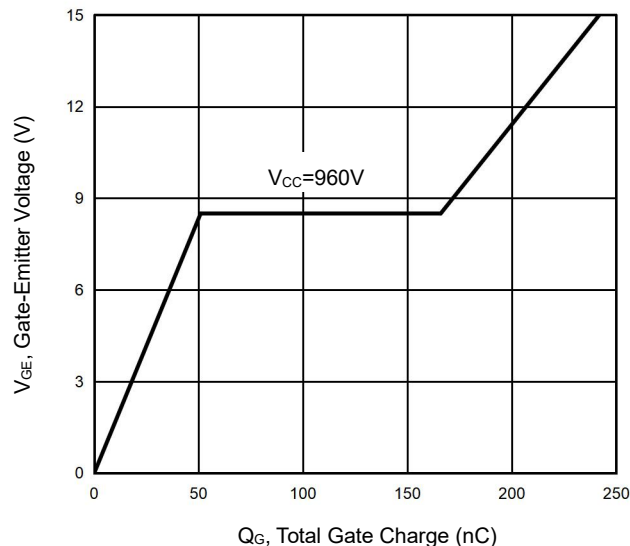


Figure 6 Gate Charge Wave Form



Typical Electrical and Thermal Characteristics

Figure 7 Forward Characteristics

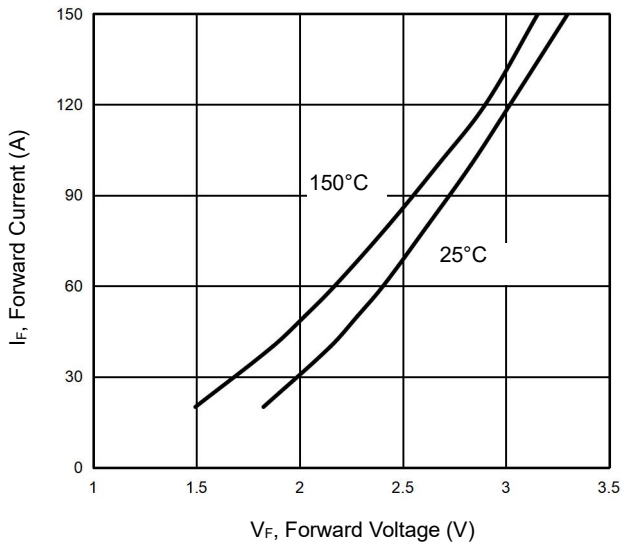


Figure 8 V_F vs. Temperature

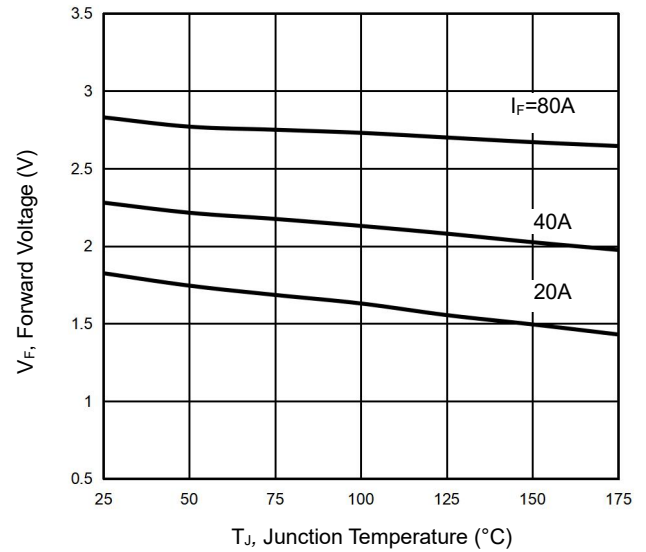


Figure 9 Switching Energy vs. Temperature

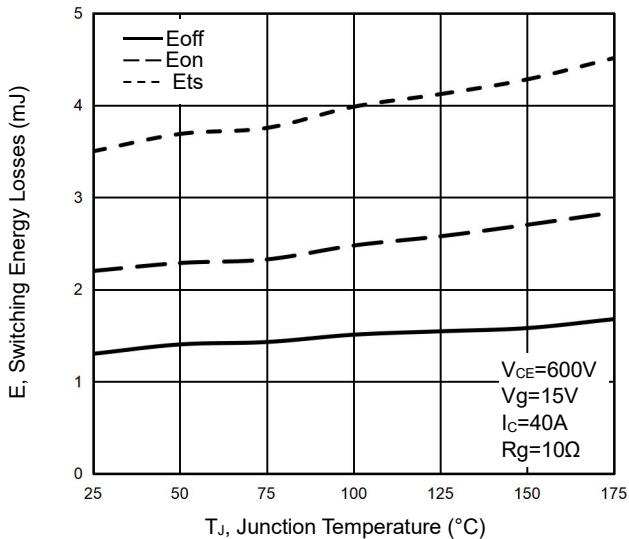


Figure 10 Forward Bias Safe Operating Area

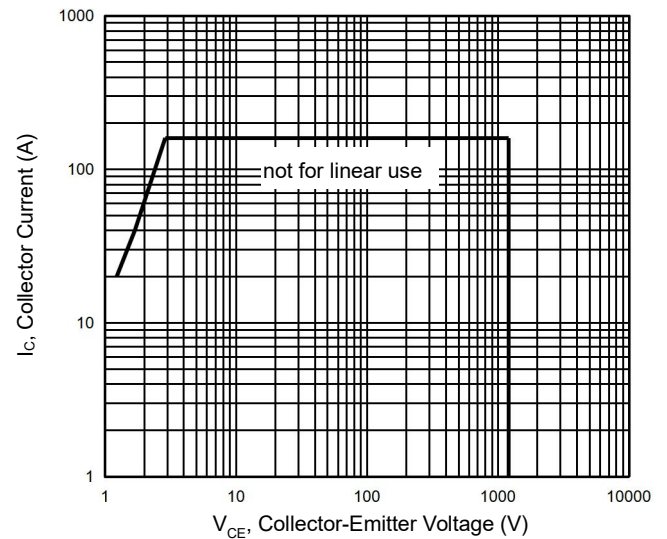


Figure 11 Gate-Emitter Threshold Voltage as a Function of Junction Temperature

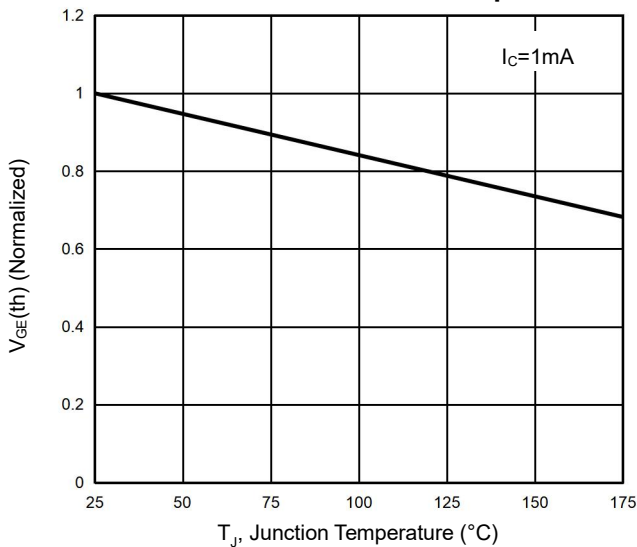
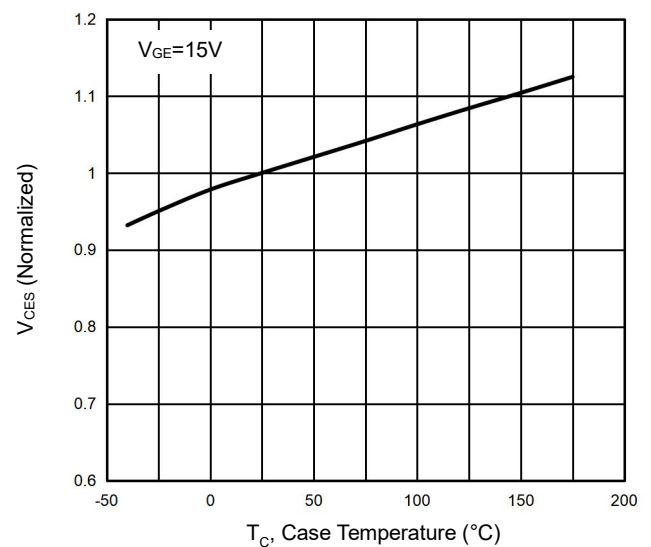
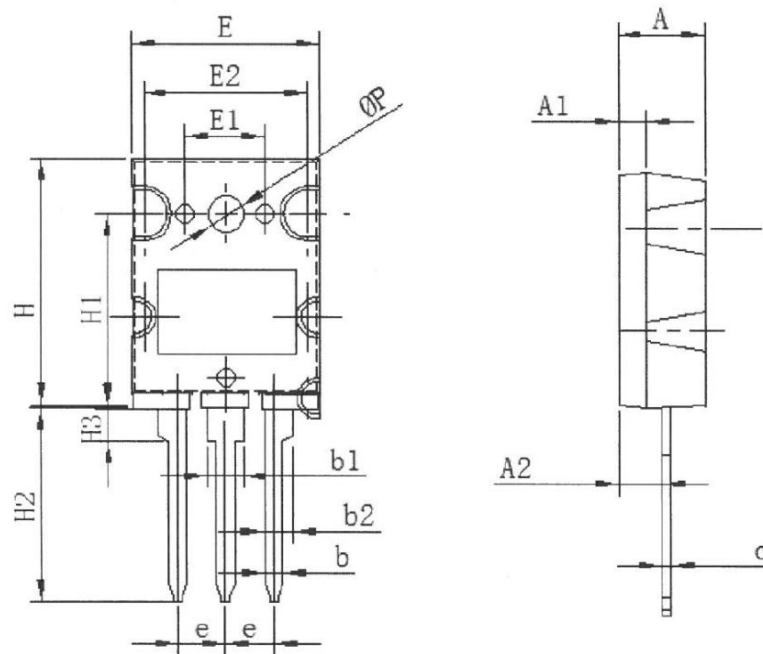


Figure 12 V_{CES} vs. Temperature



TO-264-B Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	4.80	5.20	0.18	0.20
A1	1.80	2.20	0.07	0.08
A2	3.20	3.60	0.12	0.14
b	0.80	1.20	0.03	0.04
b1	2.90	3.30	0.11	0.13
b2	2.40	2.80	0.09	0.11
c	0.50	0.70	0.02	0.03
e	5.25	5.65	0.20	0.22
E	19.80	20.20	0.78	0.79
E1	17.60	18.00	0.69	0.70
E2	8.60	9.00	0.33	0.35
H	25.80	26.20	1.01	1.03
H1	19.80	20.20	0.78	0.79
H2	19.80	20.80	0.78	0.81
H3	2.00	3.00	0.07	0.11
ØP	3.00	3.40	0.11	0.13

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